

MJE15034 NPN, MJE15035 PNP

Preferred Device

Complementary Silicon Plastic Power Transistors TO-220, NPN & PNP Devices

... designed for use as high-frequency drivers in audio amplifiers.

- $h_{FE} = 100$ (Min) @ $I_C = 0.5$ Adc
= 10 (Min) @ $I_C = 2.0$ Adc
- Collector-Emitter Sustaining Voltage –
 $V_{CEO(sus)} = 350$ Vdc (Min) – MJE15034, MJE15035
- High Current Gain – Bandwidth Product
 $f_T = 30$ MHz (Min) @ $I_C = 500$ mAdc
- TO-220AB Compact Package
- Epoxy meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Machine Model: C
Human Body Model: 3B

MAXIMUM RATINGS

Rating	Symbol	MJE15034 MJE15035	Unit
Collector-Emitter Voltage	V_{CEO}	350	Vdc
Collector-Base Voltage	V_{CB}	350	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous – Peak	I_C	4.0 8.0	Adc
Base Current	I_B	1.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.40	Watts W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2.0 0.016	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

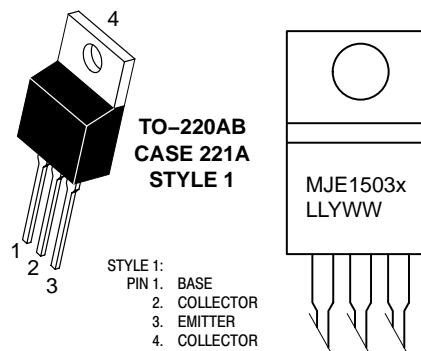


ON Semiconductor®

<http://onsemi.com>

**4.0 AMPERES
POWER TRANSISTORS
COMPLEMENTARY
SILICON
350 VOLTS
50 WATTS**

MARKING DIAGRAM & PIN ASSIGNMENT



MJE1503x = Device Code
LL = Location Code
Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MJE15034	TO-220AB	50 Units/Rail
MJE15035	TO-220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

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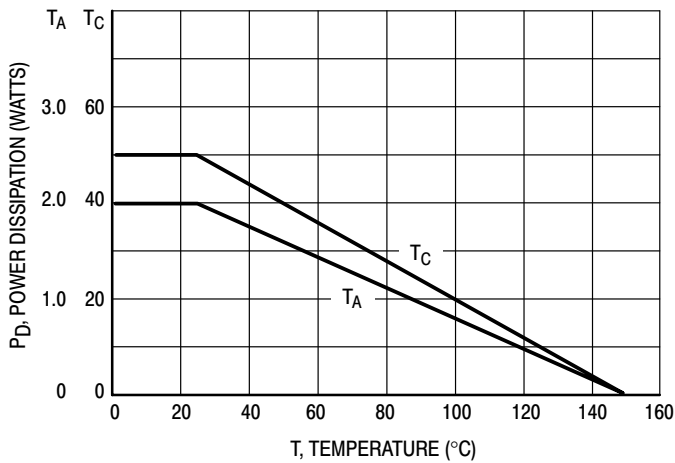


Figure 1. Power Derating

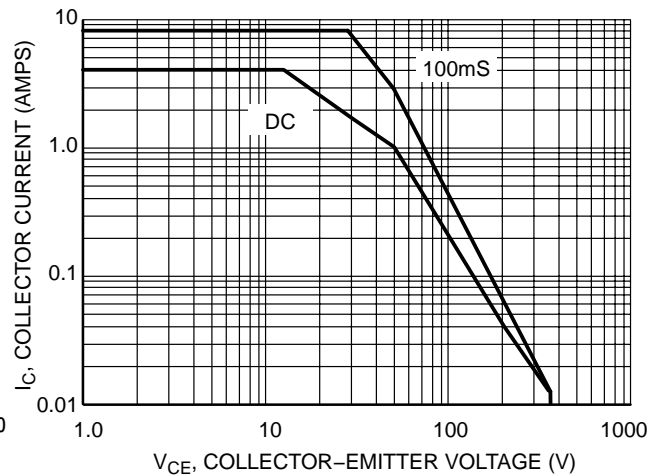


Figure 2. Active Region Safe Operating Area

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage (Note 1)	($I_C = 10\text{ mAdc}$, $I_B = 0$)	$V_{CEO(sus)}$	350	–	Vdc
Collector Cutoff Current	($V_{CB} = 350\text{ Vdc}$, $I_E = 0$)	I_{CBO}	–	10	μAdc
Emitter Cutoff Current	($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	–	10	μAdc

ON CHARACTERISTICS (Note 1)

DC Current Gain	($I_C = 0.1\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$) ($I_C = 0.5\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$) ($I_C = 1.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$)	h_{FE}	100 100 50 10	– – – –	–
Collector-Emitter Saturation Voltage	($I_C = 1.0\text{ Adc}$, $I_B = 0.1\text{ Adc}$)	$V_{CE(sat)}$	–	0.5	Vdc
Base-Emitter On Voltage	($I_C = 1.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$)	$V_{BE(on)}$	–	1.0	Vdc

DYNAMIC CHARACTERISTICS

Current Gain – Bandwidth Product (Note 2) ($I_C = 500\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 1.0\text{ MHz}$)	f_T	30	–	MHz
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1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.
2. $f_T = |h_{fe}| \cdot f_{test}$.

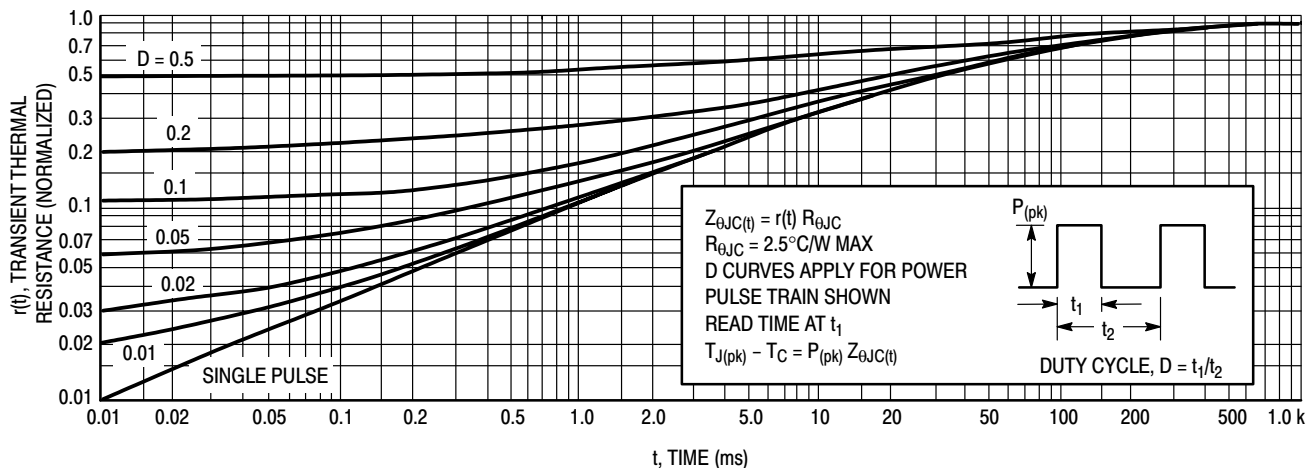
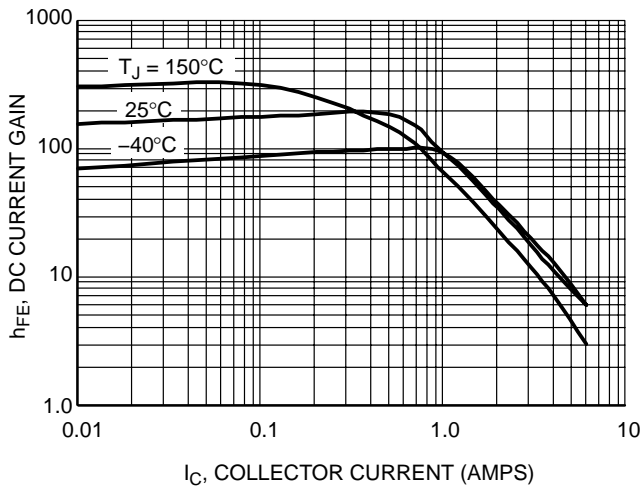
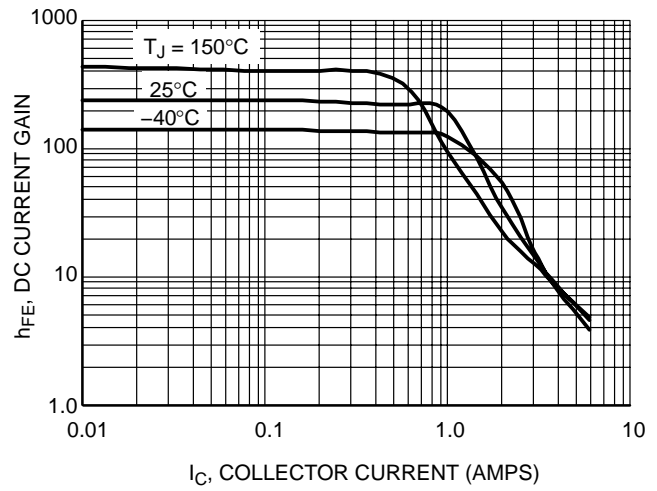


Figure 3. Thermal Response

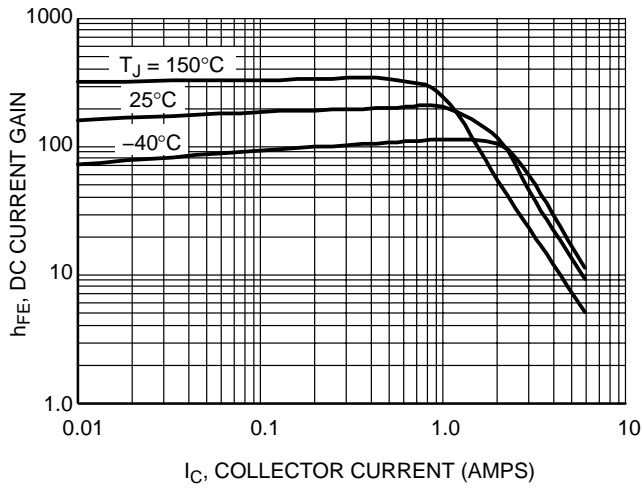
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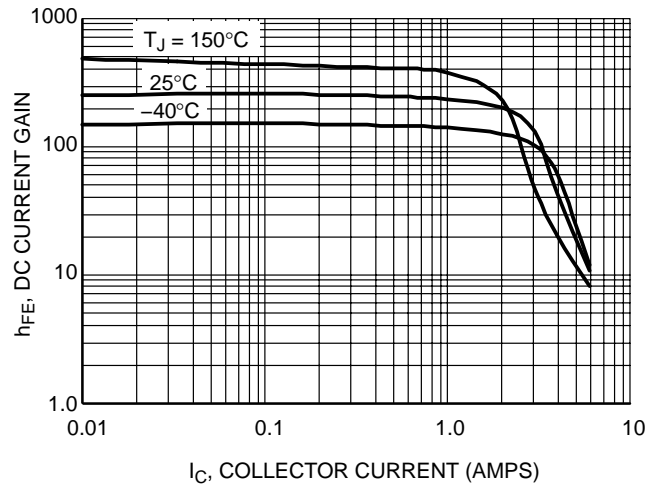
**Figure 4. DC Current Gain, $V_{CE} = 5.0$ V
NPN MJE15034**



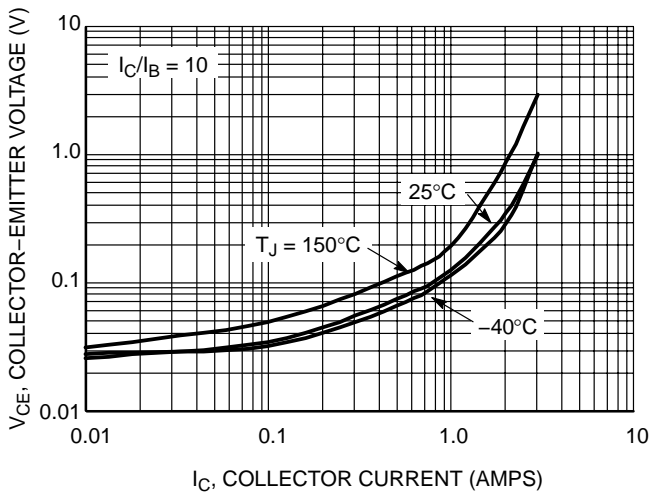
**Figure 5. DC Current Gain, $V_{CE} = 5.0$ V
PNP MJE15035**



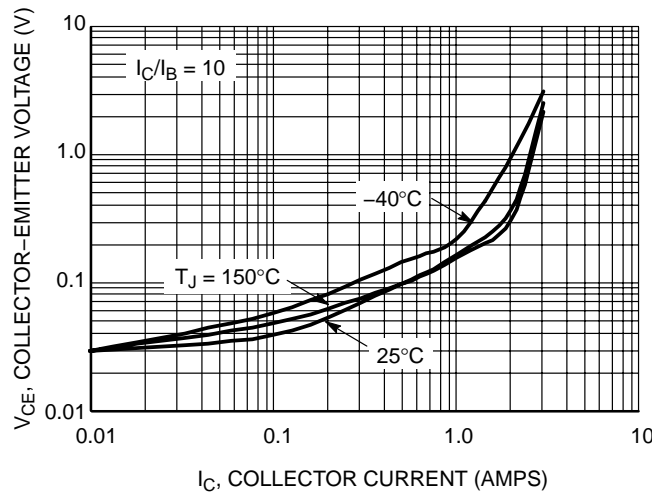
**Figure 6. DC Current Gain, $V_{CE} = 20$ V
NPN MJE15034**



**Figure 7. DC Current Gain, $V_{CE} = 20$ V
PNP MJE15035**

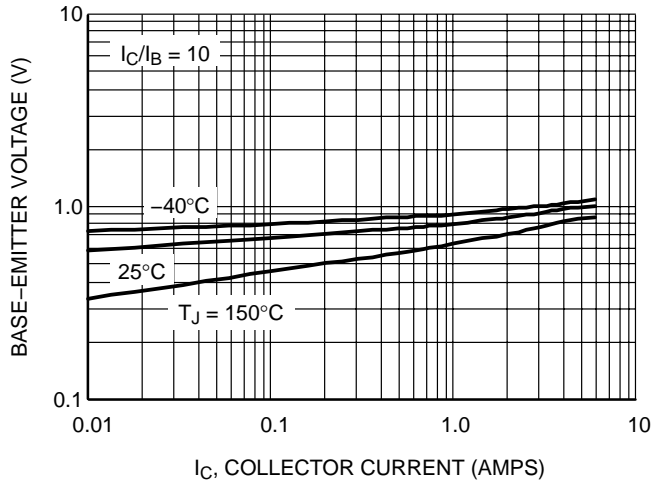


**Figure 8. $V_{CE(sat)}$
NPN MJE15034**

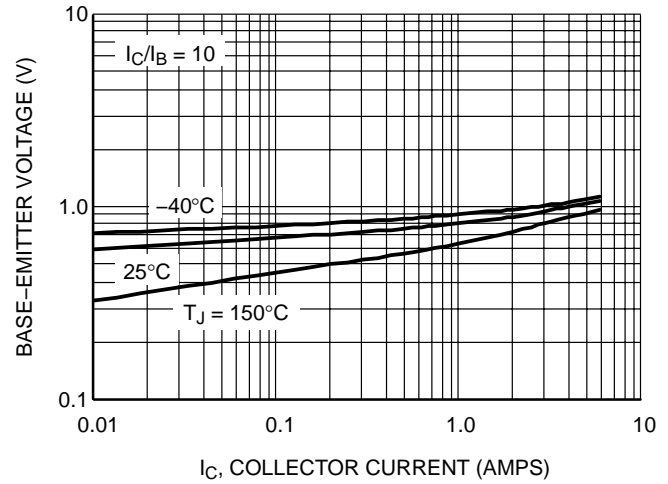


**Figure 9. $V_{CE(sat)}$
PNP MJE15035**

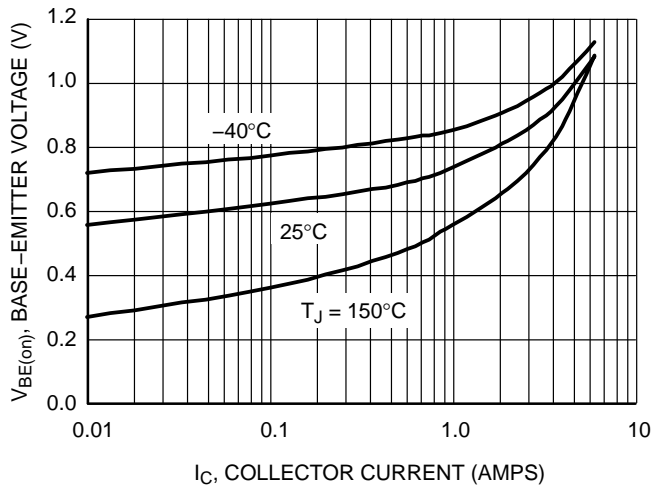
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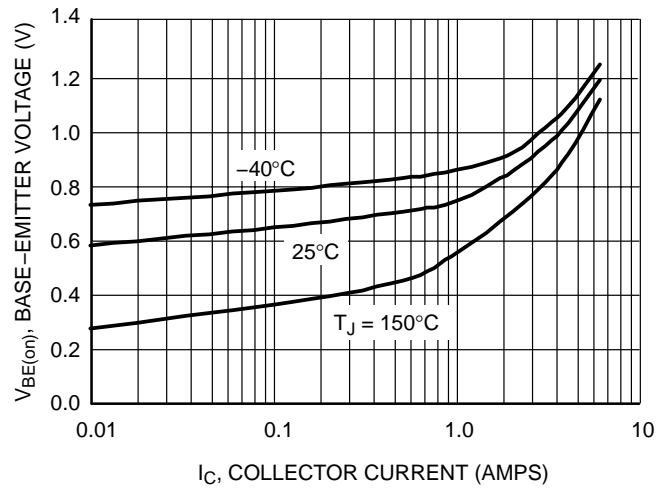
**Figure 10. $V_{BE(sat)}$
NPN MJE15034**



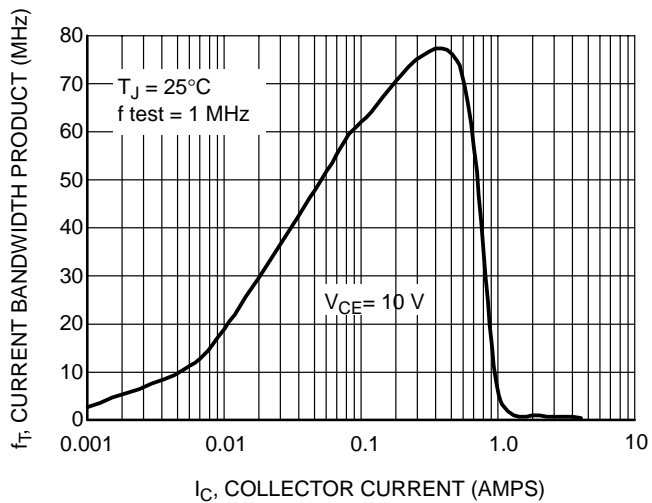
**Figure 11. $V_{BE(sat)}$
PNP MJE15035**



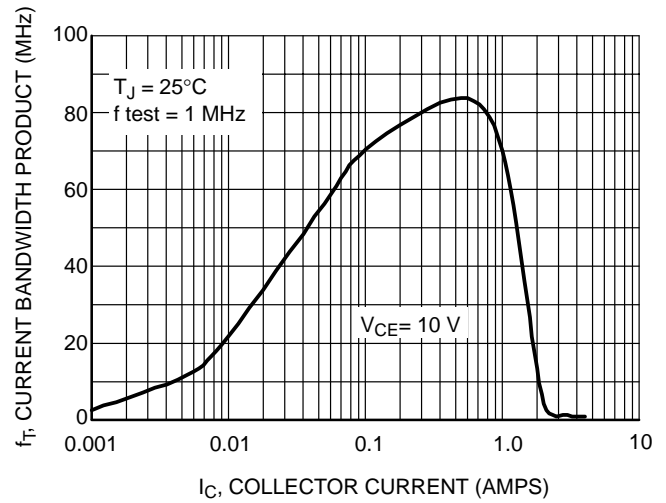
**Figure 12. $V_{BE(on)}$
NPN MJE15034**



**Figure 13. $V_{BE(on)}$
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**Figure 14. Typical Current Gain Bandwidth Product
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**Figure 15. Typical Current Gain Bandwidth Product
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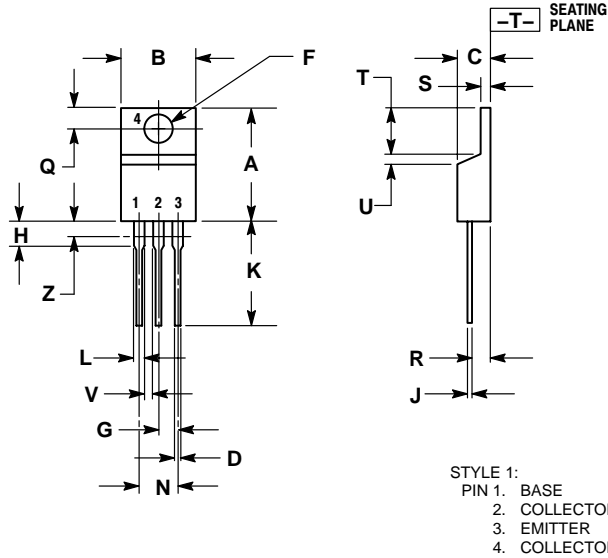
PACKAGE DIMENSIONS

TO-220 THREE-LEAD

TO-220AB

CASE 221A-09

ISSUE AA




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

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